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July 2016



FDMS86581_F085

N-Channel PowerTrench $^{\mbox{\scriptsize IR}}$ MOSFET 60 V, 30 A, 15 m Ω

Features

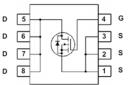
- Typical $R_{DS(on)}$ = 12.5 m Ω at V_{GS} = 10V, I_D = 30 A
- Typical $Q_{q(tot)}$ = 13 nC at V_{GS} = 10V, I_D = 25 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12V Systems







For current package drawing, please refer to the Fairchild website at https://www.fairchildsemi.com/package-drawings/PQ/PQFN08M.pdf

MOSFET Maximum Ratings $T_J = 25$ °C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V_{DSS}	Drain-to-Source Voltage		60	V
V_{GS}	Gate-to-Source Voltage		±20	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C = 25°C	30	А
ID	Pulsed Drain Current	T _C = 25°C	See Figure 4	A
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	13.5	mJ
D	Power Dissipation		50	W
P_{D}	Derate Above 25°C		0.33	W/°C
T_J , T_{STG}	Operating and Storage Temperature		-55 to + 175	°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case		3	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	50	°C/W

Notes

- 1: Current is limited by bondwire configuration.
- 2: Starting $T_J = 25^{\circ}C$, L = 40 uH, $I_{AS} = 26 \text{A}$, $V_{DD} = 60 \text{V}$ during inductor charging and $V_{DD} = 0 \text{V}$ during time in avalanche.
- 3: R_{0,JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0,JC} is guaranteed by design, while R_{0,JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86581	FDMS86581_F085	Power56	13"	12mm	3000units

Units

nΑ

Max.

±100

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted.

Parameter

Gate-to-Source Leakage Current

Off Cha	aracteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	$I_D = 250 \mu A$	V _{GS} = 0V	60	-	-	V
1	Drain-to-Source Leakage Current	V _{DS} =60V,	$T_J = 25^{\circ}C$	-	-	1	μΑ
I _{DSS} Drain-to	Dialii-to-Source Leakage Current	$V_{GS} = 0V$	$T_J = 175^{\circ}C \text{ (Note 4)}$	-	-	1	mA

 $V_{GS} = \pm 20V$

Test Conditions

Min.

Тур.

On Characteristics

Symbol

 I_{GSS}

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$		2.0	2.7	4.0	V
D	Drain to Source On Resistance	I _D = 30A,	$T_J = 25^{\circ}C$	-	12.5	15.0	$m\Omega$
R _{DS(on)}	Diani to Source On Resistance	V _{GS} = 10V	$T_J = 175^{\circ}C \text{ (Note 4)}$	-	25.1	30.1	mΩ

Dynamic Characteristics

C _{iss}	Input Capacitance	V _{DS} = 30V, V _{GS} = 0V, f = 1MHz		-	881	-	pF
C _{oss}	Output Capacitance			-	281	-	pF
C _{rss}	Reverse Transfer Capacitance	- 1 - 11VII 12		-	15	-	pF
R_g	Gate Resistance	f = 1MHz		-	3.1	-	Ω
$Q_{g(ToT)}$	Total Gate Charge	V_{GS} = 0 to 10V	V _{DD} = 30V	-	13	19	nC
Q _{g(th)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V	I _D = 25A	-	2	-	nC
Q_{gs}	Gate-to-Source Gate Charge		_	-	4	-	nC
Q_{gd}	Gate-to-Drain "Miller" Charge			-	3	-	nC

Switching Characteristics

t_{on}	Turn-On Time		-	-	20	ns
t _{d(on)}	Turn-On Delay		-	9	-	ns
t _r	Rise Time	$V_{DD} = 30V, I_{D} = 30A,$	-	5	-	ns
t _{d(off)}	Turn-Off Delay	$V_{GS} = 10V, R_{GEN} = 6\Omega$	-	15	-	ns
t _f	Fall Time		-	4	-	ns
t _{off}	Turn-Off Time		-	-	28	ns

Drain-Source Diode Characteristics

V	Source-to-Drain Diode Voltage	I _{SD} =30A, V _{GS} = 0V	-	-	1.25	V
V_{SD}	Source-to-Drain blode voltage	$I_{SD} = 15A, V_{GS} = 0V$	-	-	1.2	V
t _{rr}	Reverse-Recovery Time	I _F = 30A, dI _{SD} /dt = 100A/μs	-	37	55	ns
Q _{rr}	Reverse-Recovery Charge	V _{DD} = 48V	-	22	33	nC

Note

4: The maximum value is specified by design at T_J = 175°C. Product is not tested to this condition in production.

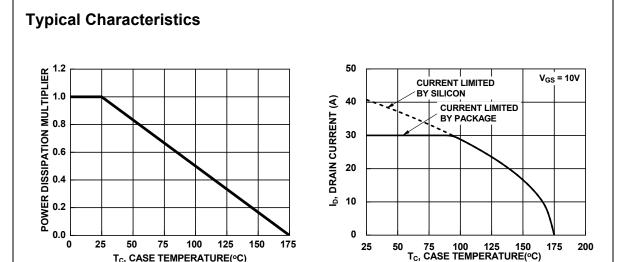


Figure 1. Normalized Power Dissipation vs. Case **Temperature**

T_C, CASE TEMPERATURE(°C)

Figure 2. Maximum Continuous Drain Current vs. **Case Temperature**

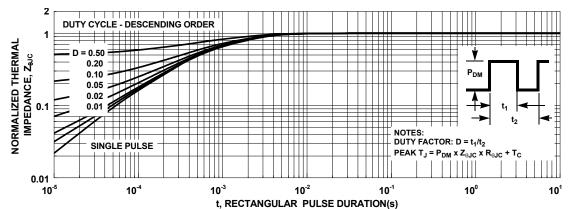


Figure 3. Normalized Maximum Transient Thermal Impedance

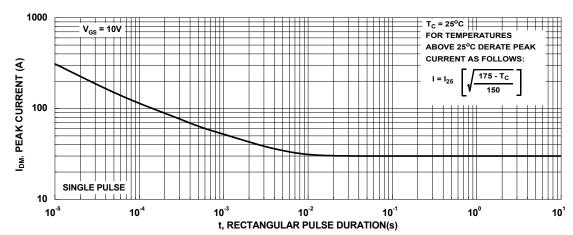


Figure 4. Peak Current Capability

Typical Characteristics

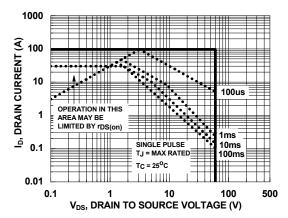
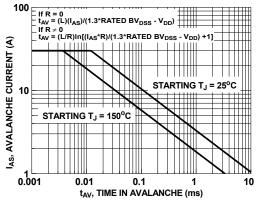


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching

Capability

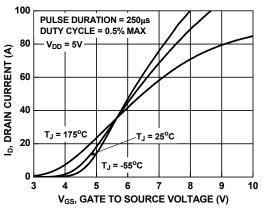


Figure 7. Transfer Characteristics

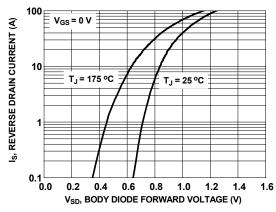


Figure 8. Forward Diode Characteristics

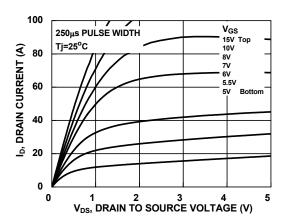


Figure 9. Saturation Characteristics

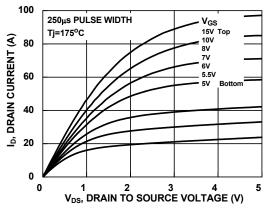


Figure 10. Saturation Characteristics

Typical Characteristics

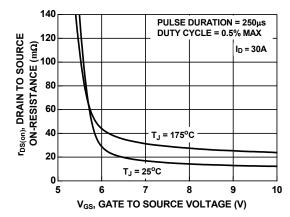


Figure 11. R_{DSON} vs. Gate Voltage

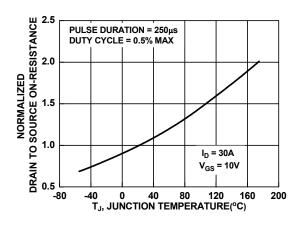


Figure 12. Normalized R_{DSON} vs. Junction Temperature

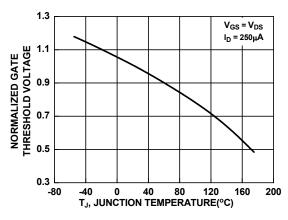


Figure 13. Normalized Gate Threshold Voltage vs. Temperature

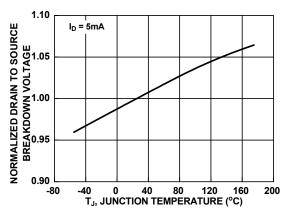


Figure 14. Normalized Drain to Source Breakdown Voltage vs. Junction Temperature

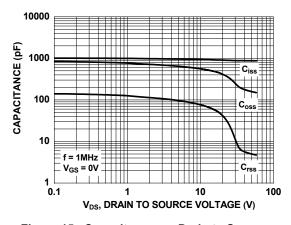


Figure 15. Capacitance vs. Drain to Source Voltage

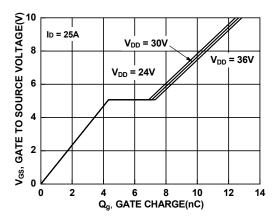


Figure 16. Gate Charge vs. Gate to Source Voltage





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